

SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

ECH8601M ---

N-Channel Silicon MOSFET **General-Purpose Switching Device Applications**

Best suited for LiB charging and discharging switch

· Built-in gate protection resistor

Halogen free compliance

Features

- · Low ON-resistance
- 2.5V drive
- Common-drain type
- Protection diode in

Specifications

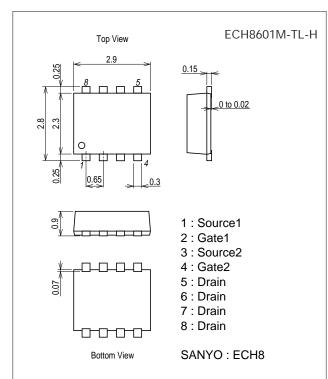
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		24	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	۱D		8	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	60	А
Allowable Power Dissipation	PD	When mounted on ceramic substrate (1000mm ² ×0.8mm) 1unit	1.5	W
Total Dissipation	PT	When mounted on ceramic substrate (1000mm ² ×0.8mm)	1.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

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Package Dimensions

unit : mm (typ.) 7011A-003



Product & Package Information : ECH8

- Package
- JEITA. JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

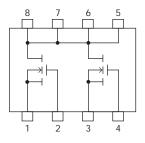
Packing Type : TL







Electrical Connection



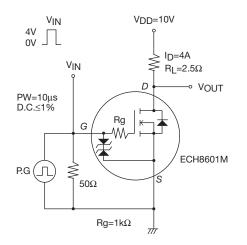
SANYO Semiconductor Co., Ltd. http://semicon.sanyo.com/en/network

50112 TKIM/72308PE TIIM TC-00001533 No. A1174-1/7

Electrical Characteristics at Ta=25°C

Denemation	Cumple al		Ratings				
Parameter	Symbol	Conditions	min.	typ.	max.	Unit	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	24			V	
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μΑ	
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ	
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	0.5		1.3	V	
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =4A	3.1	5.3		S	
	R _{DS} (on)1	ID=4A, VGS=4.5V	13.5	17	23	mΩ	
Static Drain-to-Source On-State Resistance	R _{DS} (on)2	ID=4A, VGS=4.0V	14	18	24	mΩ	
Static Drain-to-Source On-State Resistance	R _{DS} (on)3	ID=4A, VGS=3.1V	14.5	20	30	mΩ	
	RDS(on)4	ID=2A, VGS=2.5V	16	24	35	mΩ	
Turn-ON Delay Time	t _d (on)			300		ns	
Rise Time	tr			1000		ns	
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		3000		ns	
Fall Time	tf	1		1800		ns	
Total Gate Charge	Qg			7.5		nC	
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4.5V, I _D =8A		1.5		nC	
Gate-to-Drain "Miller" Charge	Qgd	1		2.0		nC	
Diode Forward Voltage	V _{SD}	IS=8A, VGS=0V		0.8	1.2	V	

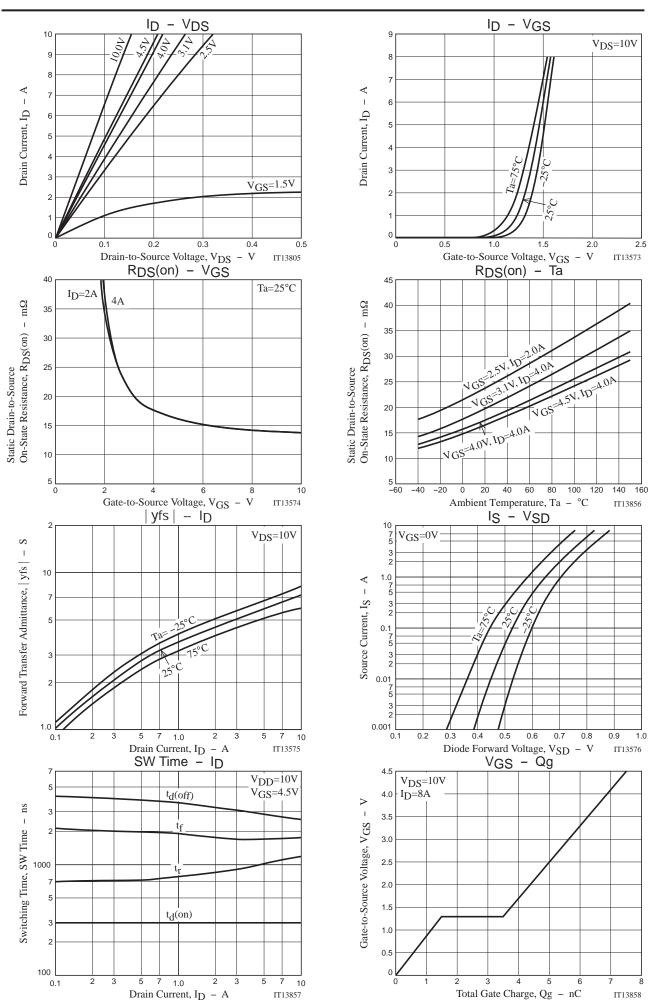
Switching Time Test Circuit

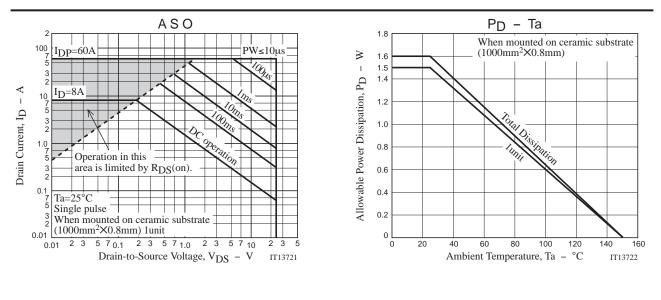


Ordering Information

Device Package		Shipping	memo	
ECH8601M-TL-H	ECH8	3,000pcs./reel	Pb-Free and Halogen Free	

ECH8601M





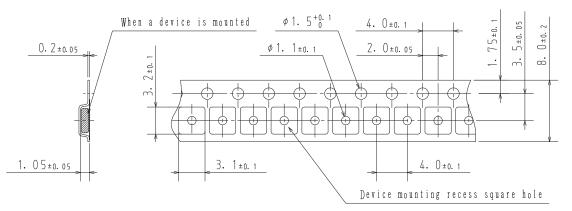
Embossed Taping Specification ECH8601M-TL-H

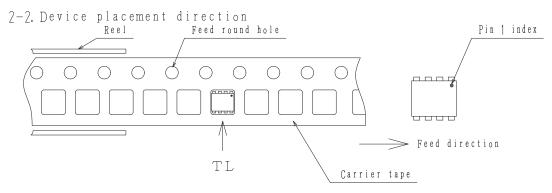
1. Packing Format

ECHO CFHO 3,000 70,000 70,000 1 Dimensions:mm (external) 183×72×185 Dimensions:mm (external) Packing method (unit:mm) Quartity Quantity Image: Comparison of a label 108 Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label Image: Comparison of a label	Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing format
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Packing method (unit:mm) It is a label at the time of factory shipme The form of a label may change in physical distribution process. Type No. 69 LOT No. (Unit:minimum minimum mini						183×72×185 440×195×210
treatment of the terminal is lead free. Label JEITA Phase LEAD FREE 3 JEITA Phase 3A	Packing met	Type LOT Quan Orig	No. tity in	-> (P. -> (P. -> (Q. ->	(u: TYPE 0000C IIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIII	nner box label Outer box label nit:mm) Tis a label at the time of factory shipments. The form of a label may change in physical distribution process. 108 000000 TYPE CODE 000000 ************************************

2. Taping configuration

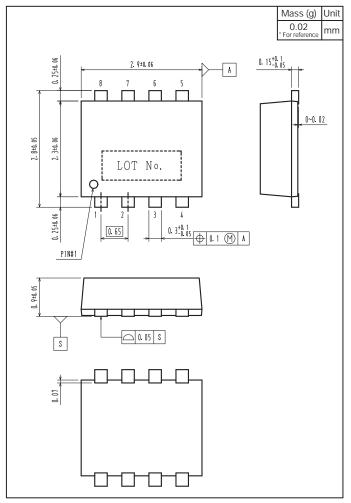
2-1. Carrier tape size (unit:mm)



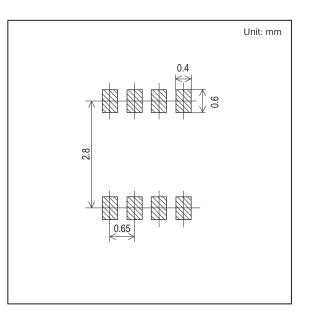


Those with pin 1 index on the feed hole side ·····TL

Outline Drawing ECH8601M-TL-H



Land Pattern Example



Note on usage : Since the ECH8601M is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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